

Middle Power Transistors (-30V / -1.0A)

Parameter	Value
V_{CEO}	-30V
I _C	-1A

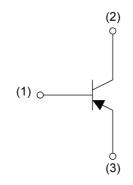
MPT3

(SC-62)

Features

- 1) Suitable for Middle Power Driver.
- 2) Complementary NPN Types: 2SCR293P5.
- 3) Low $V_{CE(sat)}$ $V_{CE(sat)}$ =-350mV(Max.). (I_C/I_B =-500mA/-25mA)

•Inner circuit



- (1) Base
- (2) Collector
- (3) Emitter

Application

LOW FREQUENCY AMPLIFIER, DRIVER

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SAR293P5	MPT3	6595	T100	330	16	1000	ML

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage		-30	V
Collector-emitter voltage	V _{CEO}	-30	V
Emitter-base voltage	V _{EBO}	-6	V
Calle atom automorph	Ic	-1	Α
Collector current	I _{CP} *1	-2	Α
Davier discinction	P _D *2	0.5	W
Power dissipation	P _D *3	2.0	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

Darameter	Sumb al	Symbol Conditions		Values		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I _C = -10μA	-30	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = -10 \mu A$	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -30V	-	1	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -6V	-	1	-100	nA
Collector-emitter saturation voltage	V _{CE(sat)} *4	$I_C = -500 \text{mA}, I_B = -25 \text{mA}$	-	-150	-350	mV
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	-	680	-
Transition frequency	f _T *4	$V_{CE} = -2V, I_{E} = 100 \text{mA},$ f = 100MHz	-	320	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	7	-	pF
Turn-On time	t _{on}	I _C = -500mA, I _{B1} = -25mA,	-	60	-	ns
Storage time	t _{stg}	$I_{B2} = 25 \text{mA},$ $V_{CC} \simeq -5 \text{V},$	-	160	-	ns
Fall time	t _f	$R_L = 10\Omega$ See test circuit	-	50	-	ns

^{*1} Pw=10ms Sigle Pulse

^{*2} Each terminal mounted on a reference land.

^{*3} Mounted on a ceramic board(40×40×0.7 mm).

^{*4} Pulsed

● Electrical characteristic curves(T_a = 25°C)

Fig.1 Grounded Emitter Propagation Characteristics

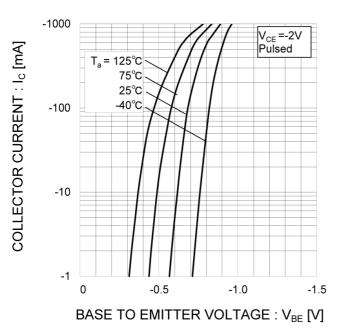
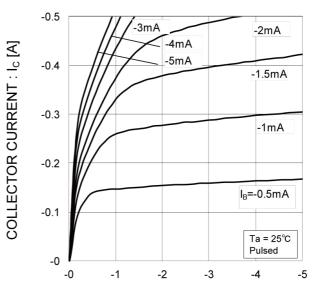


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current(I)

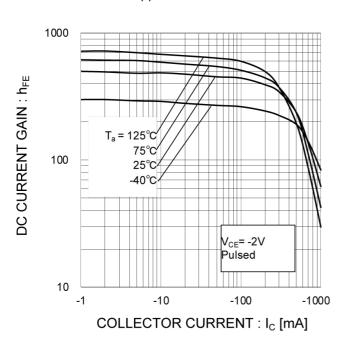
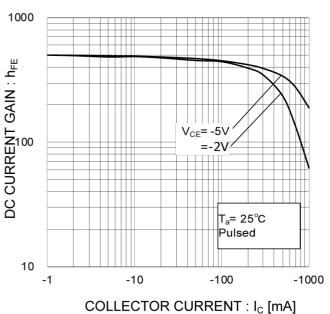


Fig.4 DC Current Gain vs. Collector Current(II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

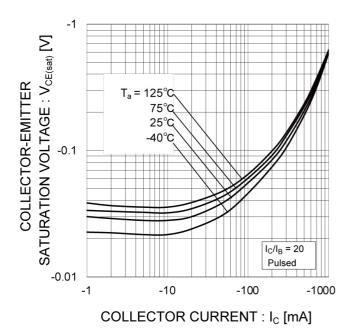


Fig.6 Collector-Emitter Saturation
Voltage vs. Collector Current(II)

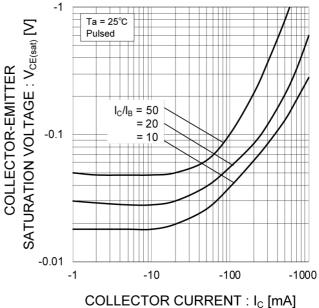


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

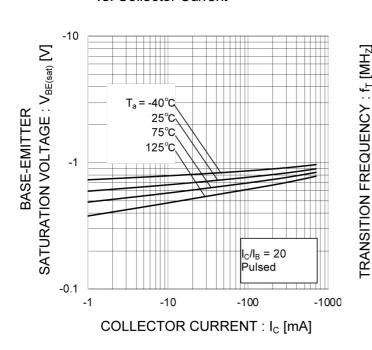
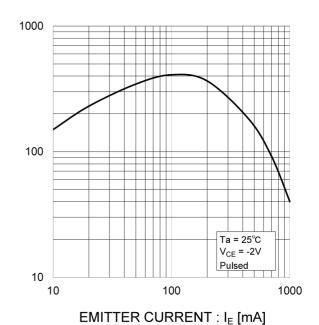


Fig.8 Gain Bandwidth Product vs. Emitter Current



● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter input capacitance vs.Emitter-Base Voltage Collector output capacitance vs. Collector-Base Voltage

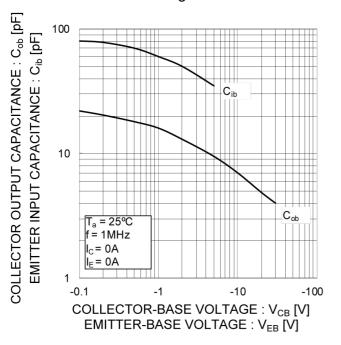
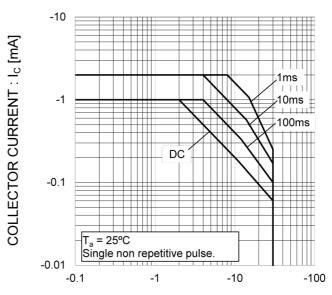
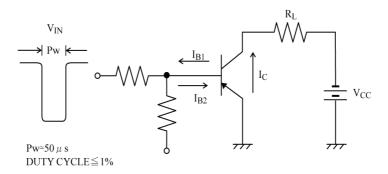


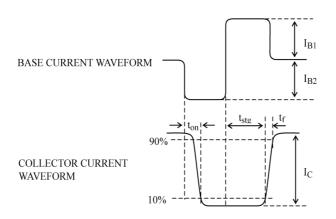
Fig.10 Safe Operating Area



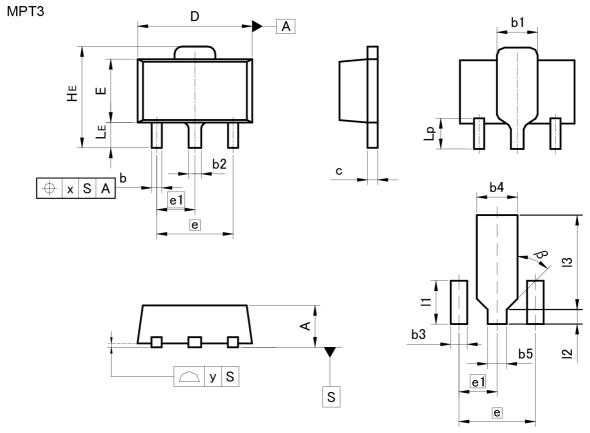
COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

SWITCHING TIME TEST CIRCUIT





Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.40	1.50	0.055	0.059
b	0.30	0.50	0.012	0.020
b1	1.50	1.70	0.059	0.067
b2	0.40	0.60	0.016	0.024
С	0.35	0.50	0.014	0.020
D	4.40	4.70	0.173	0.185
E	2.40	2.70	0.094	0.106
е	3.0	3.00		18
e1	1.3	1.50		159
HE	3.70	4.30	0.146	0.169
LE	0.80	1.20	0.031	0.047
Lp	1.01	1.41	0.040	0.056
х	-	0.15	-	0.006
У	-	0.10	_	0.004

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b3	-	0.65	_	0.026	
b4	_	1.70	_	0.067	
b5	-	0.75	_	0.030	
l1	-	1.71	_	0.067	
12	-	0.58	_	0.023	
13	-	3.72	-	0.146	
R	45°		45	0	

6/6

Dimension in mm/inches



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2sar293p5 - Web Page

Distribution Inventory

Part Number	2sar293p5
Package	MPT3
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes